NSN 5962-01-234-8033

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
525.0 milliwatts
Operating Tempurature Range:
-0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+125.0 degrees celsius
Features Provided:
Ultraviolet erasable and programmable and static operation
Output Logic Form:
Metal oxide-semiconductor logic
Input Circuit Pattern:
13 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 6.0 volts power source
Time Rating Per Chacteristic:
450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Fiig:
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